

5HN01SS

MOSFET, Silicon, N-Channel Ultrahigh-Speed Switching Applications

Features

- Low ON-resistance
- Ultrahigh-speed Switching
- 4 V Drive
- These Devices are Pb-Free and are RoHS Compliant

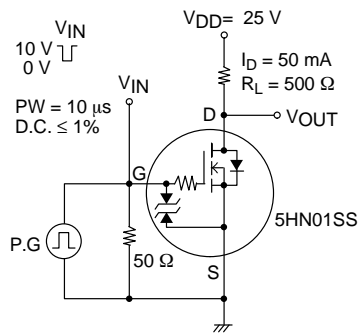


Figure 1. Switching Time Test Circuit

NOTE: Since the 5HN01SS is designed for high-speed switching applications, please avoid using this device in the vicinity of highly charged objects.

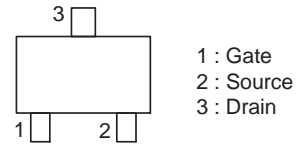


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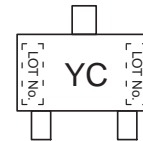
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SOT-623 / SSFP
CASE 631AC



MARKING DIAGRAM



YC = Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

5HN01SS

SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		50	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		0.1	A
Drain Current (Pulse)	I _{DP}	PW ≤ 10 μs, duty cycle ≤ 1%	0.4	A
Allowable Power Dissipation	P _D		0.15	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ELECTRICAL CHARACTERISTICS at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			Min	Typ	Max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D = 1 mA, V _{GS} = 0	50			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} = 50 V, V _{GS} = 0			1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} = ±16 V, V _{DS} = 0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = -100 μA	1		2.4	V
Forward Transfer Admittance	y _{fs}	V _{DS} = 10 V, I _D = 50 mA	85	120		mS
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D = 50 mA, V _{GS} = 10 V		5.8	7.5	Ω
	R _{DS(on)2}	I _D = 30 mA, V _{GS} = 4 V		7.5	10.5	Ω
Input Capacitance	C _{iss}	V _{DS} = 10 V, f = 1 MHz		6.2		pF
Output Capacitance	C _{oss}	V _{DS} = 10 V, f = 1 MHz		4.4		pF
Reverse Transfer Capacitance	C _{rss}	V _{DS} = 10 V, f = 1 MHz		1.5		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit		10		ns
Rise Time	t _r	See specified Test Circuit		11		ns
Turn-OFF Delay Time	t _{d(off)}	See specified Test Circuit		105		ns
Fall Time	t _f	See specified Test Circuit		75		ns
Total Gate Charge	Q _g	V _{DS} = 10 V, V _{GS} = 10 V, I _D = 100 mA		1.40		nC
Gate Source Charge	Q _{gs}	V _{DS} = 10 V, V _{GS} = 10 V, I _D = 100 mA		0.21		nC
Gate Drain Charge	Q _{gd}	V _{DS} = 10 V, V _{GS} = 10 V, I _D = 100 mA		0.34		nC
Diode Forward Voltage	V _{SD}	I _S = 100 mA, V _{GS} = 0		0.85	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS

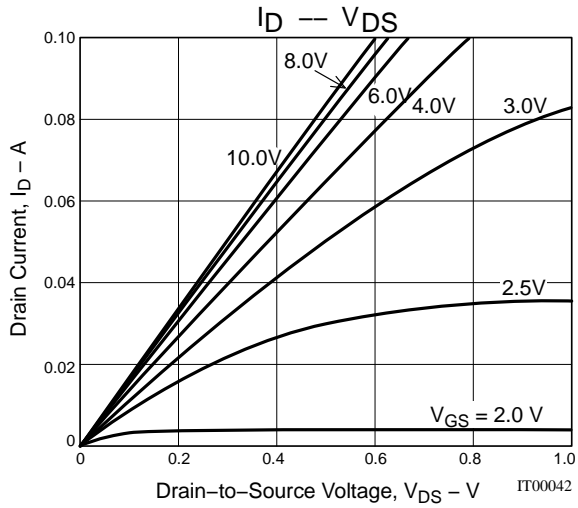


Figure 2.

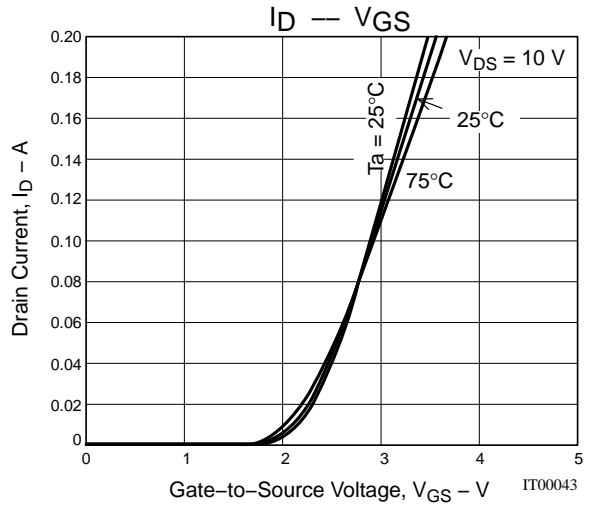


Figure 3.

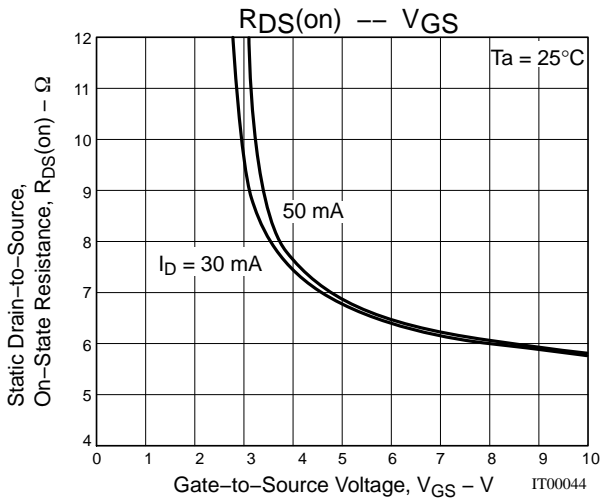


Figure 4.

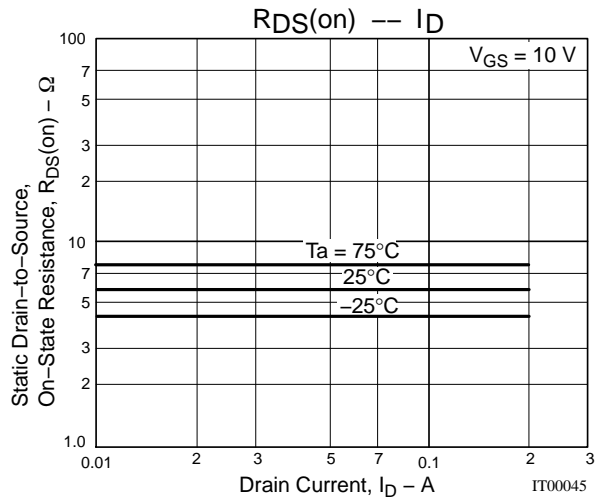


Figure 5.

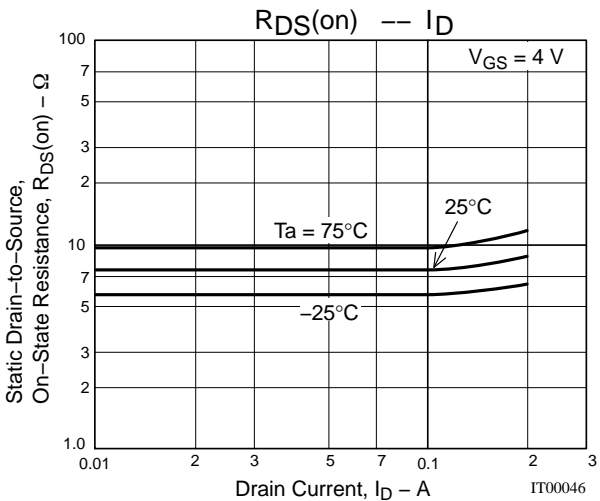


Figure 6.

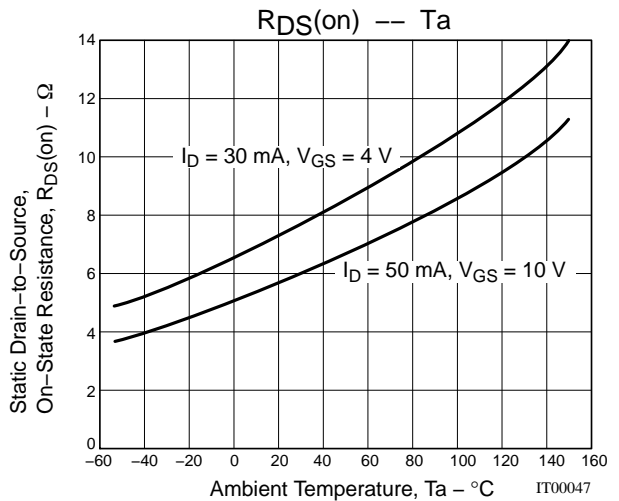


Figure 7.

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TYPICAL CHARACTERISTICS

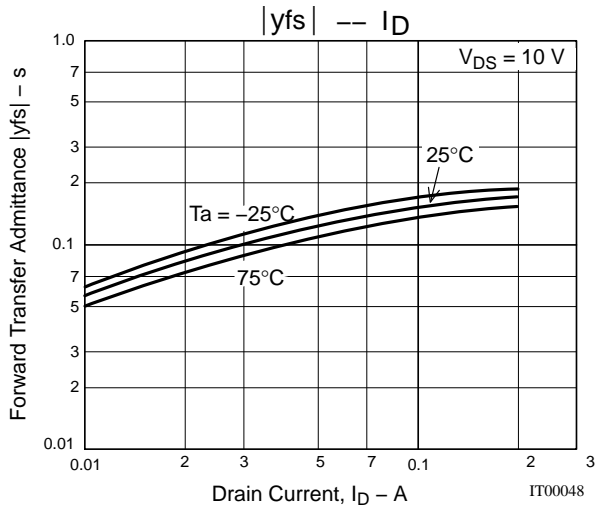


Figure 8.

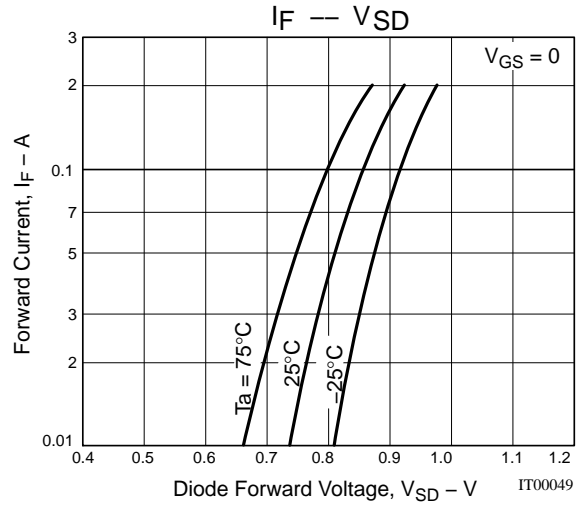


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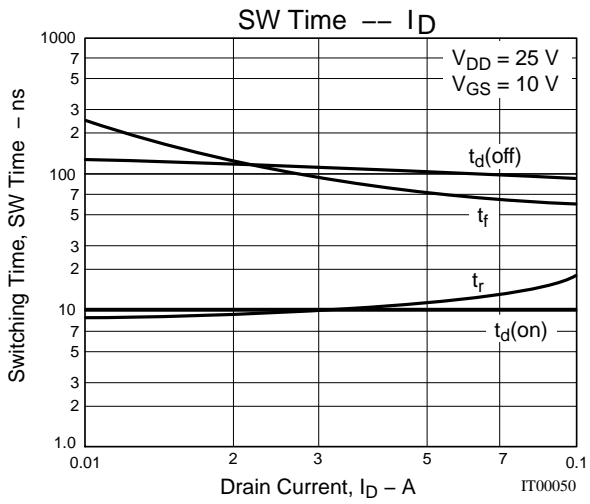


Figure 10.

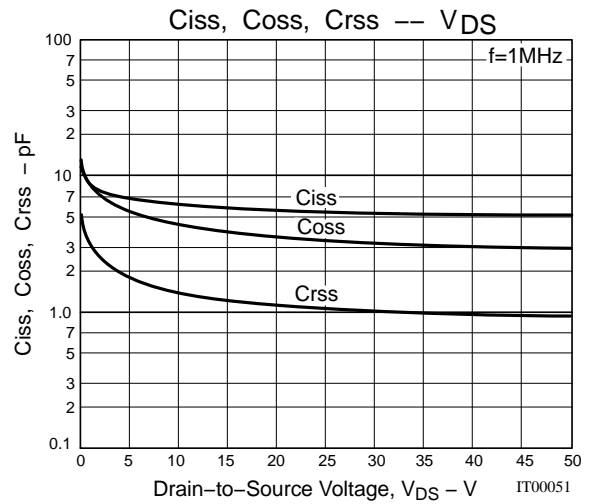


Figure 11.

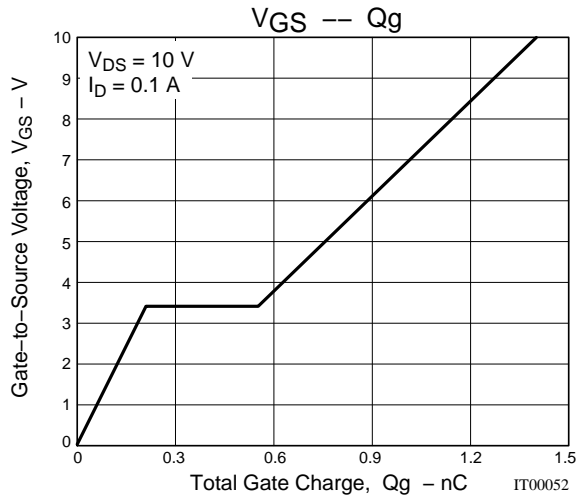


Figure 12.

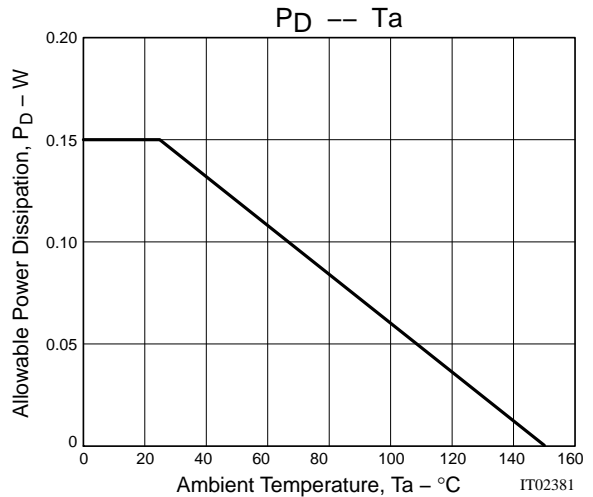
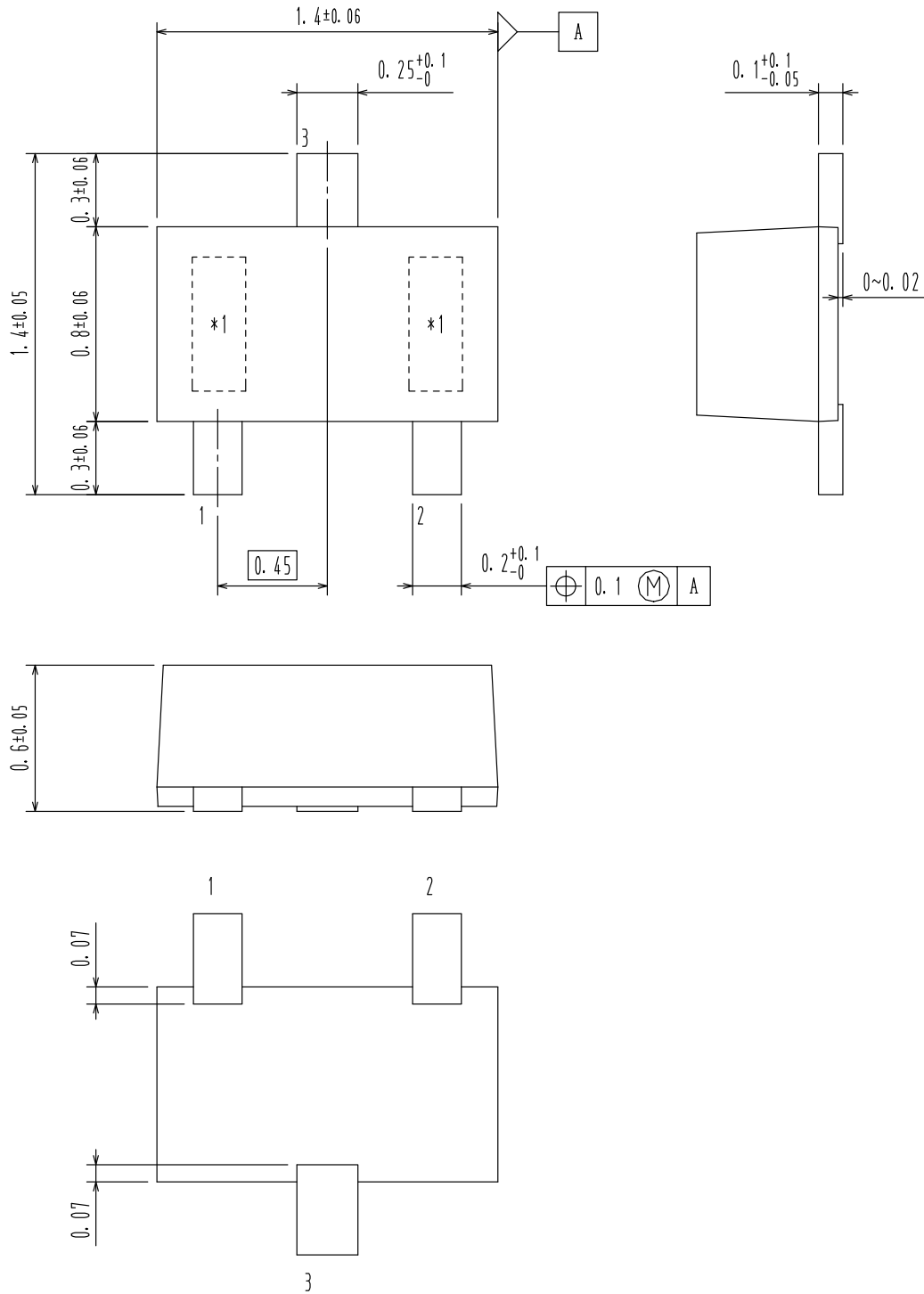


Figure 13.

5HN01SS

PACKAGE DIMENSIONS

SOT-623 / SSFP
CASE 631AC
ISSUE O




5HN01SS

ORDERING INFORMATION

Device	Marking	Package	Shipping†
5HN01SS-TL-E / 5HN01SS-TL-H	YC	SOT-623 / SSFP (Pb-Free / Halogen Free)	8,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D

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